3Q Hi-Com Triac Rev. 02 — 29 November 2010

Product data sheet

1. Product profile

1.1 General description

Planar passivated high commutation three quadrant triac in a SOT78 plastic package intended for use in circuits where high static and dynamic dV/dt and high dl/dt can occur. This "series C" triac will commutate the full RMS current at the maximum rated junction temperature without the aid of a snubber.

1.2 Features and benefits

- 3Q technology for improved noise immunity
- High commutation capability with maximum false trigger immunity
- High immunity to false turn-on by dV/dt

1.3 Applications

- Electronic thermostats (heating and cooling)
- High power motor controls e.g. washing machines and vacuum cleaners

1.4 Quick reference data

- High voltage capability
- Planar passivated for voltage ruggedness and reliability
- Triggering in three quadrants only
- Rectifier-fed DC inductive loads e.g. DC motors and solenoids

Table 1.	Quick reference da	ata				
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{DRM}	repetitive peak off-state voltage		-	-	800	V
I _{TSM}	non-repetitive peak on-state current	full sine wave; $T_{j(init)} = 25 \text{ °C};$ $t_p = 20 \text{ ms}; \text{ see } Figure 4;$ see Figure 5	-	-	95	A
I _{T(RMS)}	RMS on-state current	full sine wave; T _{mb} ≤ 101 °C; see <u>Figure 3</u> ; see <u>Figure 1</u> ; see <u>Figure 2</u>	-	-	12	A



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Table 1.	Quick reference	datacontinued				
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	aracteristics					
.......	gate trigger current	V _D = 12 V; I _T = 0.1 A; T2+ G+; T _j = 25 °C; see <u>Figure 7</u>	2	-	35	mA
		$V_D = 12 V; I_T = 0.1 A; T2+ G-;$ $T_j = 25 °C; see Figure 7$	2	-	35	mA
		$V_D = 12 V; I_T = 0.1 A; T2-G-;$ $T_j = 25 °C; see Figure 7$	2	-	35	mA

Table 1 Outlate rafe .

Pinning information 2.

Table 2	. Pinniı	ng information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	T1	main terminal 1		N.
2	T2	main terminal 2	mb	
3	G	gate		Sym051
mb	Τ2	mounting base; main terminal 2		

SOT78 (TO-220AB)

Ordering information 3.

Table 3. Ordering information						
Type number	Package					
	Name	Description	Version			
BTA312-800C	TO-220AB	plastic single-ended package; heatsink mounted; 1 mounting hole; 3-lead TO-220AB	SOT78			

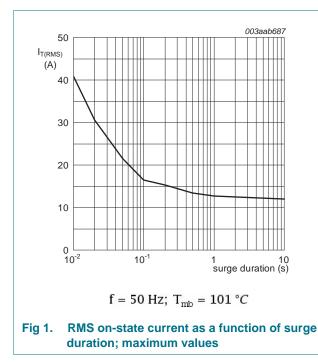
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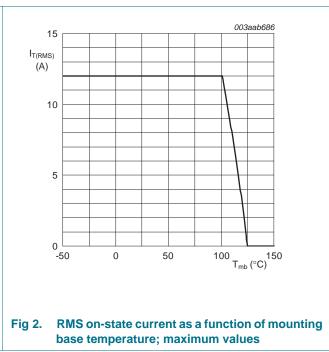
4. Limiting values

Table 4. Limiting values

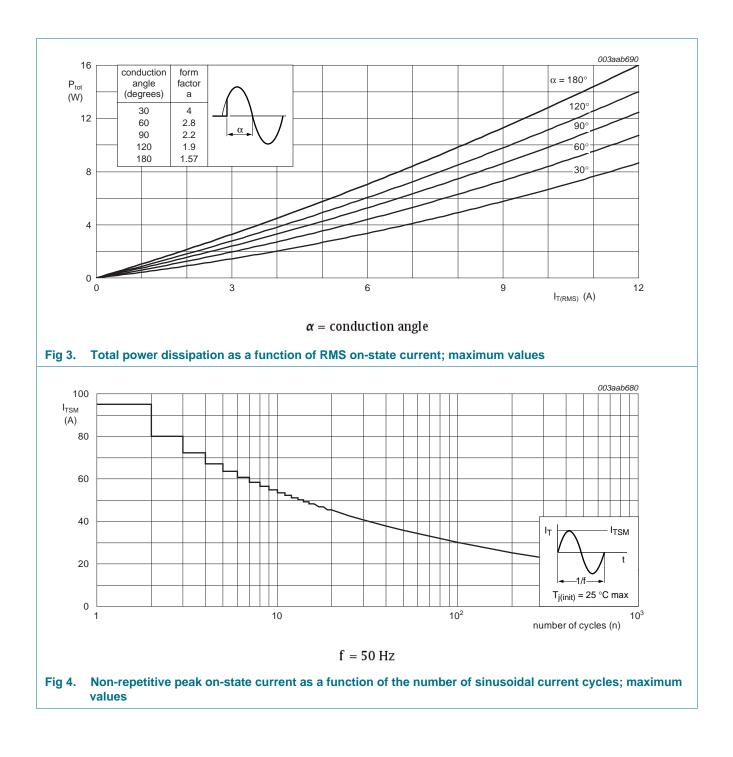
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{DRM}	repetitive peak off-state voltage		-	800	V
I _{T(RMS)}	RMS on-state current	full sine wave; T _{mb} ≤ 101 °C; see <u>Figure 3</u> ; see <u>Figure 1</u> ; see <u>Figure 2</u>	-	12	A
I _{TSM}	non-repetitive peak on-state current	full sine wave; T _{j(init)} = 25 °C; t _p = 20 ms; see <u>Figure 4</u> ; see <u>Figure 5</u>	-	95	А
		full sine wave; $T_{j(init)} = 25 \text{ °C};$ t _p = 16.7 ms	-	105	А
l ² t	I ² t for fusing	t _p = 10 ms; sine-wave pulse	-	45	A ² s
dl _T /dt	rate of rise of on-state current	I_T = 20 A; I_G = 0.2 A; dI_G/dt = 0.2 A/µs	-	100	A/µs
I _{GM}	peak gate current		-	2	А
P _{GM}	peak gate power		-	5	W
P _{G(AV)}	average gate power	over any 20 ms period	-	0.5	W
T _{stg}	storage temperature		-40	150	°C
Tj	junction temperature		-	125	°C

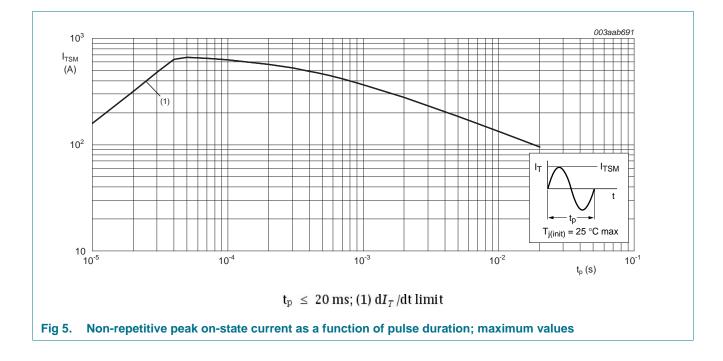




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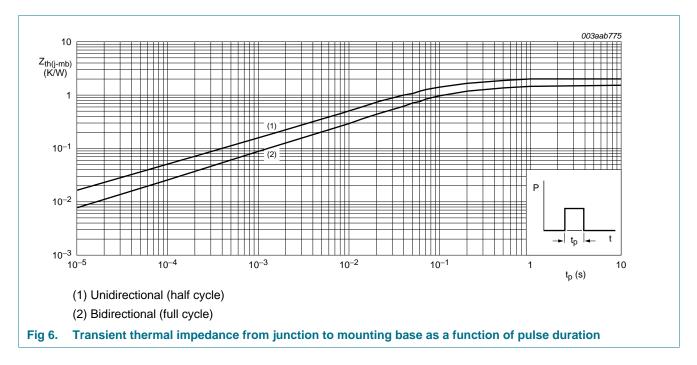
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5. Thermal characteristics

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Table 5.	Thermal characteristics					
Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
ui(j-110)	thermal resistance	full cycle; see Figure 6	-	-	1.5	K/W
	from junction to mounting base	half cycle; see Figure 6	-	-	2	K/W
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	-	60	-	K/W



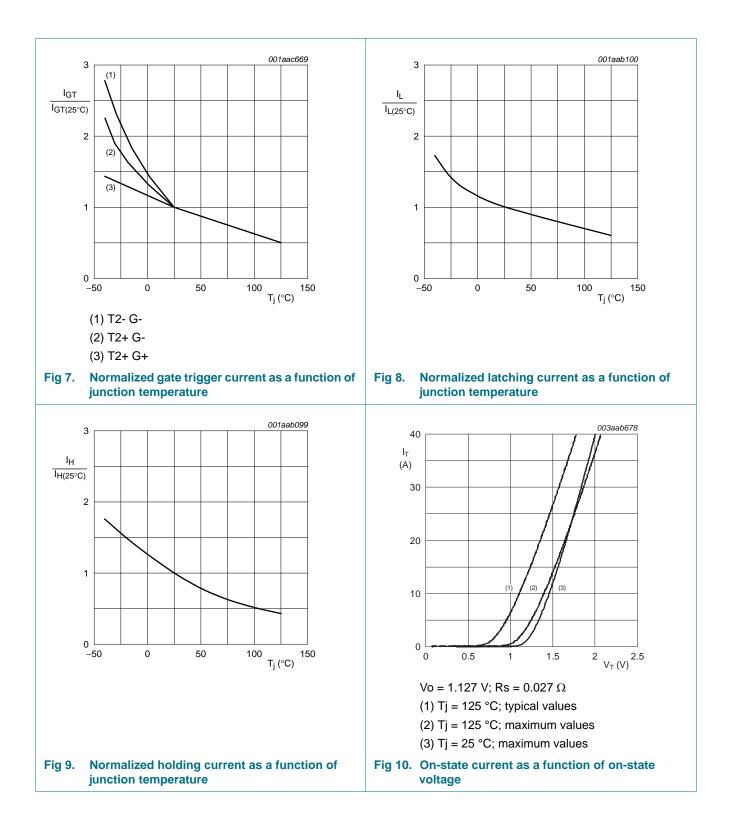
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6. Characteristics

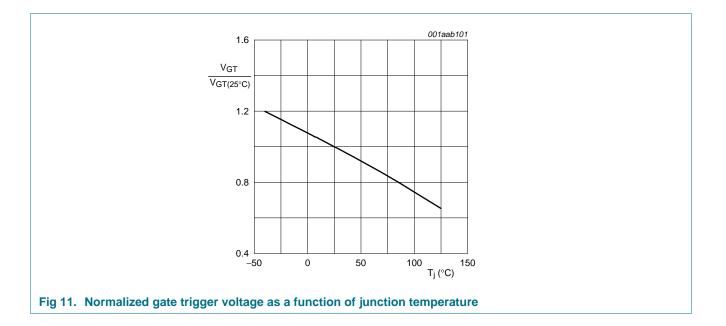
Table 6.	Characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	aracteristics					
I _{GT}	gate trigger current	V _D = 12 V; I _T = 0.1 A; T2+ G+; T _j = 25 °C; see <u>Figure 7</u>	2	-	35	mA
		V _D = 12 V; I _T = 0.1 A; T2+ G-; T _j = 25 °C; see <u>Figure 7</u>	2	-	35	mA
		V _D = 12 V; I _T = 0.1 A; T2- G-; T _j = 25 °C; see <u>Figure 7</u>	2	-	35	mA
ΙL	latching current	V _D = 12 V; I _G = 0.1 A; T2+ G+; T _j = 25 °C; see <u>Figure 8</u>	-	-	50	mA
		V _D = 12 V; I _G = 0.1 A; T2+ G-; T _j = 25 °C; see <u>Figure 8</u>	-	-	60	mA
		V _D = 12 V; I _G = 0.1 A; T2- G-; T _j = 25 °C; see <u>Figure 8</u>	-	-	50	mA
I _H	holding current	$V_D = 12 \text{ V}; \text{ T}_j = 25 \text{ °C}; \text{ see } \frac{\text{Figure 9}}{100000000000000000000000000000000000$	-	-	35	mA
VT	on-state voltage	I _T = 15 A; T _j = 25 °C; see <u>Figure 10</u>	-	1.3	1.6	V
V _{GT}	gate trigger voltage	V _D = 12 V; I _T = 0.1 A; T _j = 25 °C; see <u>Figure 11</u>	-	0.8	1.5	V
		V _D = 400 V; I _T = 0.1 A; T _j = 125 °C; see <u>Figure 11</u>	0.25	0.4	-	V
I _D	off-state current	$V_{D} = 800 \text{ V}; \text{ T}_{j} = 125 \text{ °C}$	-	0.1	0.5	mA
Dynamic	characteristics					
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 536 V; T_j = 125 °C; exponential waveform; gate open circuit	500	-	-	V/µs
dl _{com} /dt	rate of change of commutating current	$V_D = 400 \text{ V}; \text{ T}_j = 125 \text{ °C}; \text{ I}_{T(RMS)} = 12 \text{ A};$ $dV_{com}/dt = 20 \text{ V}/\mu\text{s};$ gate open circuit; "without snubber" condition	20	-	-	A/ms
t _{gt}	gate-controlled turn-on time	$I_{TM} = 20 \text{ A}; \text{V}_{\text{D}} = 800 \text{V}; \text{I}_{\text{G}} = 0.1 \text{A}; \\ \text{d} \text{I}_{\text{G}}/\text{d} \text{t} = 5 \text{A}/\mu\text{s}$	-	2	-	μs

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Package outline 7.

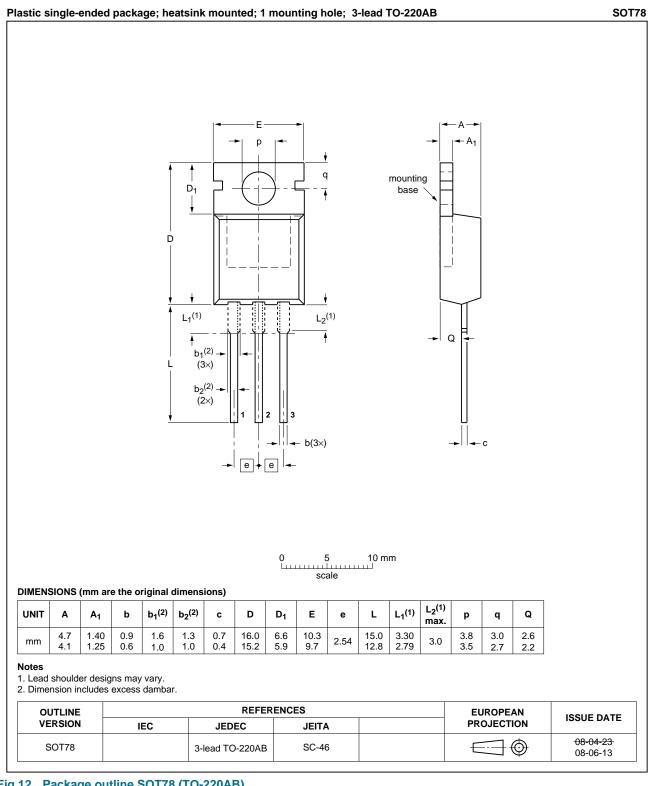


Fig 12. Package outline SOT78 (TO-220AB)

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8. Revision history

Table 7. Revision hi	story			
Document ID	Release date	Data sheet status	Change notice	Supersedes
BTA312-800C v.2	20101129	Product data sheet	-	BTA312_SER_B_C v.1
Modifications:	 Type number BTA3 	12-800C separated from	data sheet BTA312_SEF	R_B_C v.1.
	 Various changes to 	content.		
BTA312_SER_B_C v.1	20070313	Product data sheet	-	-

9. Legal information

9.1 Data sheet status

Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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